Electrical Characteristics (continued)

Unless otherwise specified: Vcc = 3.3 V ± 5%, Vcco = 3.3 V ± 5%, 2.5 V ± 5%, -40 °C ≤ T_A ≤ 85 °C, CLKin driven differentially, input slew rate ≥ 3 V/ns. Typical values represent most likely parametric norms at Vcc = 3.3 V, Vcco = 3.3 V, T_A = 25 °C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured. [1][2]

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
LVPECL OUTPUTS (CLKoutAn/CLKoutAn*, CLKoutBn/CLKoutBn*)							
f_{CLKout_FS}	Maximum Output Frequency Full V_{OD} Swing[5][10]	V_{OD} ≥ 600 mV, R_L = 100 Ω differential	Vcco = 3.3 V ± 5%, R_T = 160 Ω to GND	1.0	1.2		GHz
			Vcco = 2.5 V ± 5%, R_T = 91 Ω to GND	0.75	1.0		
f_{CLKout_RS}	Maximum Output Frequency Reduced V_{OD} Swing[5][10]	V_{OD} ≥ 400 mV, R_L = 100 Ω differential	Vcco = 3.3 V ± 5%, R_T = 160 Ω to GND	1.5	3.1		GHz
			Vcco = 2.5 V ± 5%, R_T = 91 Ω to GND	1.5	2.3		
$Jitter_{ADD}$	Additive RMS Jitter, Integration Bandwidth 10 kHz to 20 MHz[5][11][12]	Vcco = 2.5 V ± 5%: R_T = 91 Ω to GND, Vcco = 3.3 V ± 5%: R_T = 160 Ω to GND, R_L = 100 Ω differential	CLKin: 100 MHz, Slew rate ≥ 3 V/ns		77	98	fs
			CLKin: 156.25 MHz, Slew rate ≥ 3 V/ns		54	78	
$Jitter_{ADD}$	Additive RMS Jitter Integration Bandwidth 1 MHz to 20 MHz[11]	Vcco = 3.3 V, R_T = 160 Ω to GND, R_L = 100 Ω differential	CLKin: 100 MHz, Slew rate ≥ 3 V/ns		59		fs
			CLKin: 156.25 MHz, Slew rate ≥ 2.7 V/ns		64		
			CLKin: 625 MHz, Slew rate ≥ 3 V/ns		30		
$Jitter_{ADD}$	Additive RMS Jitter with LVPECL clock source from LMK03806[11][13]	Vcco = 3.3 V, R_T = 160 Ω to GND, R_L = 100 Ω differential	CLKin: 156.25 MHz, J_{SOURCE} = 190 fs RMS (10 kHz to 1 MHz)		20		fs
			CLKin: 156.25 MHz, J_{SOURCE} = 195 fs RMS (12 kHz to 20 MHz)		51		
Noise Floor	Noise Floor f_{OFFSET} ≥ 10 MHz[14][15]	Vcco = 3.3 V, R_T = 160 Ω to GND, R_L = 100 Ω differential	CLKin: 100 MHz, Slew rate ≥ 3 V/ns		-162.5		dBc/Hz
			CLKin: 156.25 MHz, Slew rate ≥ 2.7 V/ns		-158.1		
			CLKin: 625 MHz, Slew rate ≥ 3 V/ns		-154.4		
DUTY	Duty Cycle[5]	50% input clock duty cycle		45%		55%	
V_{OH}	Output High Voltage	T_A = 25 °C, DC Measurement, R_T = 50 Ω to Vcco - 2 V		Vcco - 1.2	Vcco - 0.9	Vcco - 0.7	V
V_{OL}	Output Low Voltage			Vcco - 2.0	Vcco - 1.75	Vcco - 1.5	V
V_{OD}	Output Voltage Swing[6]			600	830	1000	mV

(10) See *Typical Characteristics* for output operation over frequency.
(11) For the 100 MHz and 156.25 MHz clock input conditions, Additive RMS Jitter (J_{ADD}) is calculated using Method #1: J_{ADD} = SQRT(J_{OUT}^2 - J_{SOURCE}^2), where J_{OUT} is the total RMS jitter measured at the output driver and J_{SOURCE} is the RMS jitter of the clock source applied to CLKin. For the 625 MHz clock input condition, Additive RMS Jitter is approximated using Method #2: J_{ADD} = SQRT(2*$10^{dBc/10}$) / (2*π*f_{CLK}), where dBc is the phase noise power of the Output Noise Floor integrated from 1 to 20 MHz bandwidth. The phase noise power can be calculated as: dBc = Noise Floor + 10*log_{10}(20 MHz - 1 MHz). The additive RMS jitter was approximated for 625 MHz using Method #2 because the RMS jitter of the clock source was not sufficiently low enough to allow practical use of Method #1. Refer to the "Noise Floor vs. CLKin Slew Rate" and "RMS Jitter vs. CLKin Slew Rate" plots in *Typical Characteristics*.
(12) 100 MHz and 156.25 MHz input source from Rohde & Schwarz SMA100A Low-Noise Signal Generator and Sine-to-Square-wave Conversion block.
(13) 156.25 MHz LVPECL clock source from LMK03806 with 20 MHz crystal reference (crystal part number: ECS-200-20-30BU-DU). J_{SOURCE} = 190 fs RMS (10 kHz to 1 MHz) and 195 fs RMS (12 kHz to 20 MHz). Refer to the LMK03806 datasheet for more information.
(14) The noise floor of the output buffer is measured as the far-out phase noise of the buffer. Typically this offset is ≥ 10 MHz, but for lower frequencies this measurement offset can be as low as 5 MHz due to measurement equipment limitations.
(15) Phase noise floor will degrade as the clock input slew rate is reduced. Compared to a single-ended clock, a differential clock input (LVPECL, LVDS) will be less susceptible to degradation in noise floor at lower slew rates due to its common mode noise rejection. However, it is recommended to use the highest possible input slew rate for differential clocks to achieve optimal noise floor performance at the device outputs.

Electrical Characteristics (continued)

Unless otherwise specified: Vcc = 3.3 V ± 5%, Vcco = 3.3 V ± 5%, 2.5 V ± 5%, -40 °C ≤ T_A ≤ 85 °C, CLKin driven differentially, input slew rate ≥ 3 V/ns. Typical values represent most likely parametric norms at Vcc = 3.3 V, Vcco = 3.3 V, T_A = 25 °C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured. [1][2]

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
PROPAGATION DELAY and OUTPUT SKEW							
t_{PD_PECL}	Propagation Delay CLKin-to-LVPECL[7]	R_T = 160 Ω to GND, R_L = 100 Ω differential, C_L ≤ 5 pF		180	360	540	ps
t_{PD_LVDS}	Propagation Delay CLKin-to-LVDS[7]	R_L = 100 Ω differential, CL ≤ 5 pF		200	400	600	ps
t_{PD_HCSL}	Propagation Delay CLKin-to-HCSL[7][16]	R_T = 50 Ω to GND, C_L ≤ 5 pF		295	590	885	ps
t_{PD_CMOS}	Propagation Delay CLKin-to-LVCMOS[7][16]	C_L ≤ 5 pF	Vcco = 3.3 V	900	1475	2300	ps
			Vcco = 2.5 V	1000	1550	2700	
$t_{SK(O)}$	Output Skew LVPECL/LVDS/HCSL [5][16][18]	Skew specified between any two CLKouts with the same buffer type. Load conditions per output type are the same as propagation delay specifications.			30	50	ps
$t_{SK(PP)}$	Part-to-Part Output Skew LVPECL/LVDS/HCSL [7][16][18]				80	120	ps

(18) Output skew is the propagation delay difference between any two outputs with identical output buffer type and equal loading while operating at the same supply voltage and temperature conditions.